

# NCP4894

## Audio Power Amplifier, 1.8 Watt, with Selectable Shutdown

The NCP4894 is a differential audio power amplifier designed for portable communication device applications. This feature and the excellent audio characteristics of the NCP4894 are a guarantee of a high quality sound, for example, in mobile phones applications. With a 10% THD+N value the NCP4894 is capable of delivering 1.8 W of continuous average power to an 8.0  $\Omega$  load from a 5.5 V power supply. With the same load conditions and a 5.0 V battery voltage, it ensures 1.0 W to be delivered with less than 0.01% distortion.

The NCP4894 provides high quality audio while requiring few external components and minimal power consumption. It features a low-power consumption shutdown mode.

To be flexible, shutdown may be enabled by either a logic high or low depending on the voltage applied on the SD MODE pin.

The NCP4894 contains circuitry to prevent from “pop and click” noise that would otherwise occur during turn-on and turn-off transitions.

For maximum flexibility, the NCP4894 provides an externally controlled gain (with resistors), as well as an externally controlled turn-on time (with bypass capacitor).

Due to its excellent PSRR, it can be directly connected to the battery, saving the use of an LDO.

This device is available in 9-Pin Flip-Chip, Micro-10 and DFN10 3x3 mm packages.

### Features

- Differential Amplification
- Shutdown High or Low Selectivity
- 1.0 W to an 8.0  $\Omega$  Load from a 5.0 V Power Supply
- Superior PSRR: Direct Connection to the Battery
- “Pop and Click” Noise Protection Circuit
- Ultra Low Current Shutdown Mode
- 2.2 V–5.5 V Operation
- External Gain Configuration Capability
- External Turn-on Configuration Capability
- Thermal Overload Protection Circuitry
- Pb-Free Packages are Available

### Typical Applications

- Portable Electronic Devices
- PDAs
- Mobile Phones



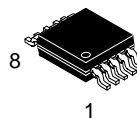
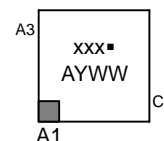
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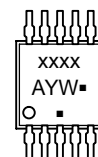
### MARKING DIAGRAMS



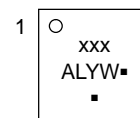
9-PIN FLIP-CHIP  
FC SUFFIX  
CASE 499AL



Micro-10  
DM SUFFIX  
CASE 846B



DFN10  
MN SUFFIX  
CASE 485C



xxxx = Specific Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W, WW = Work Week  
▪ = Pb-Free Package  
(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 15 of this data sheet.

# NCP4894

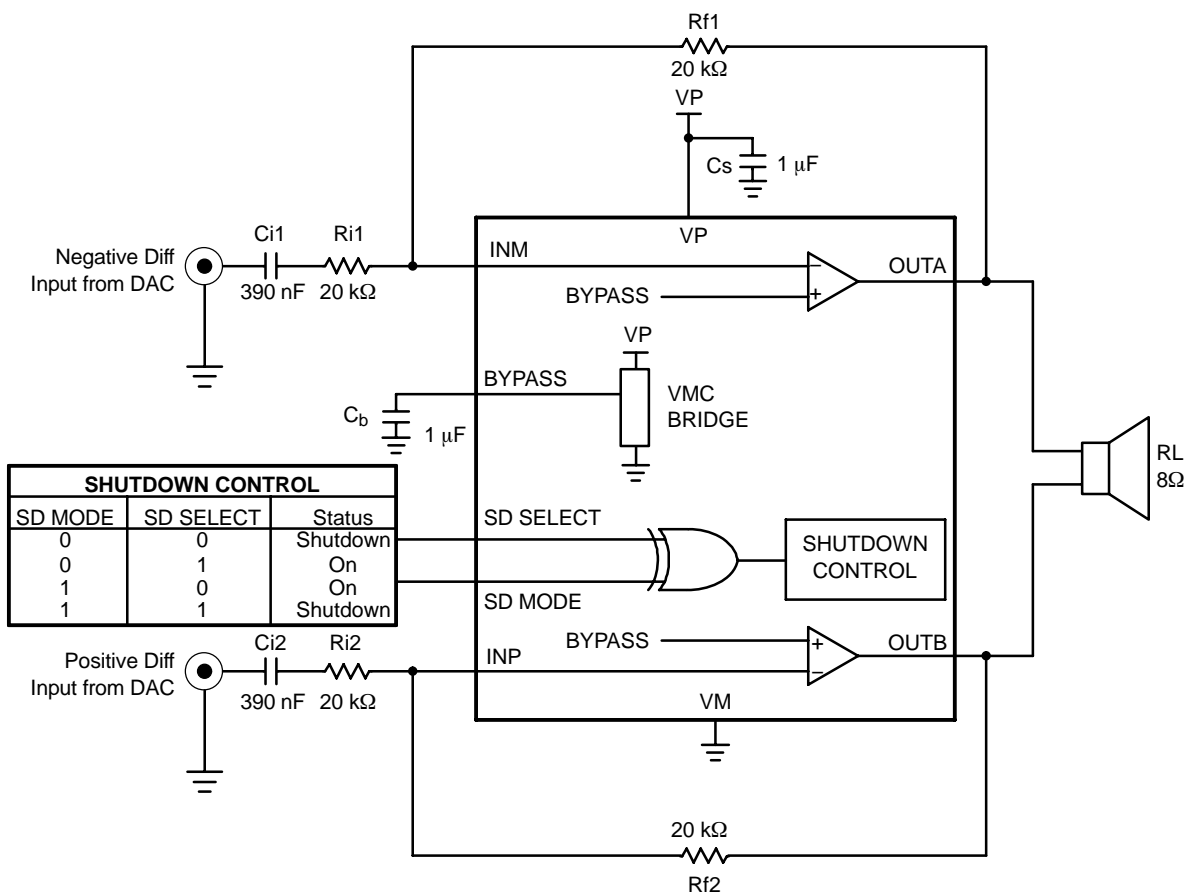


Figure 1. Typical NCP4894 Application Circuit with Differential Input

# NCP4894

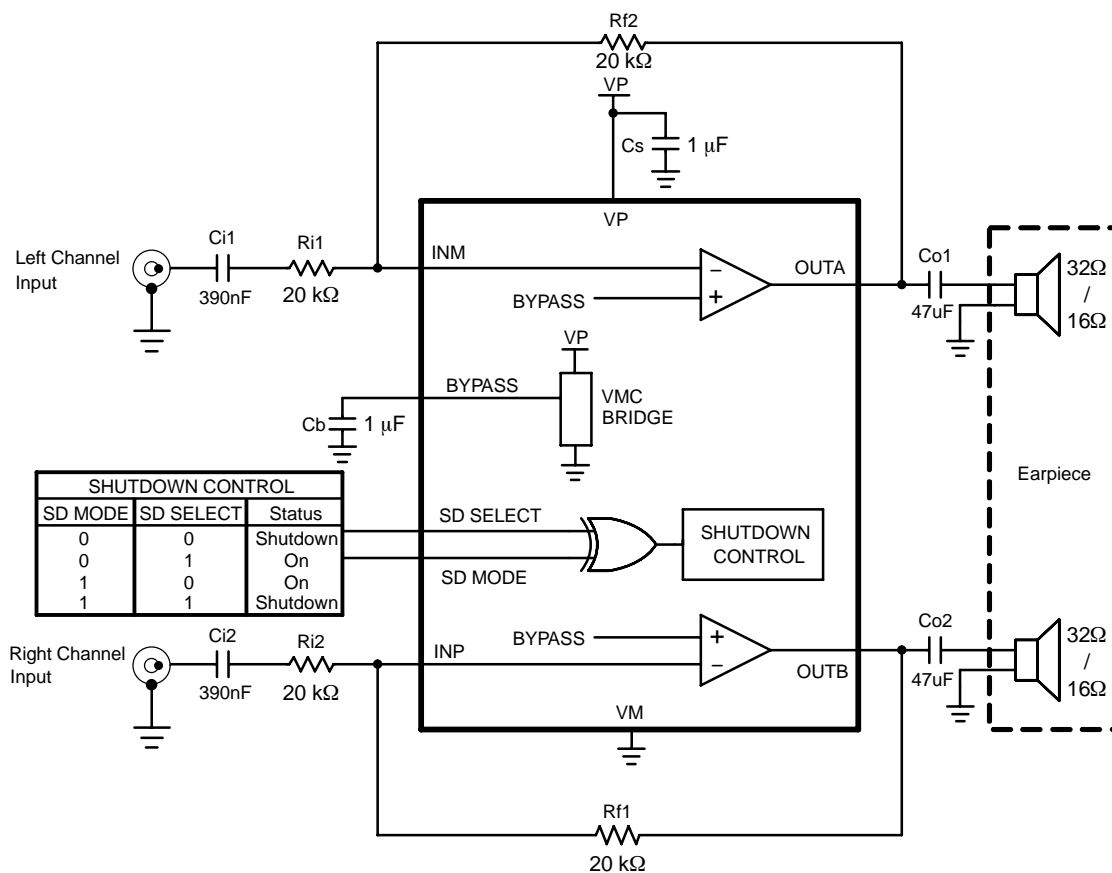
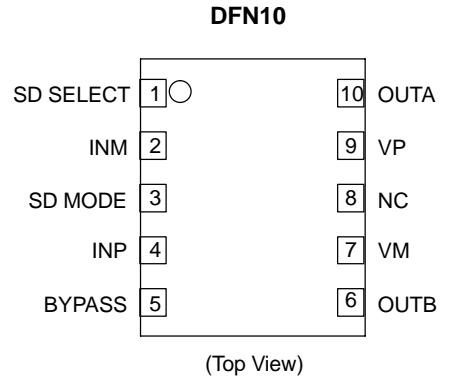
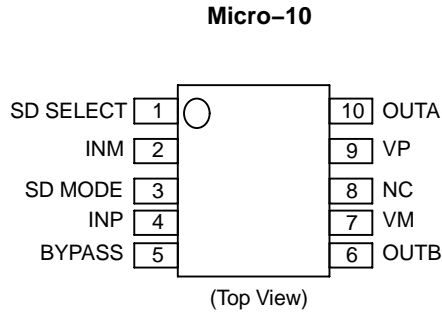
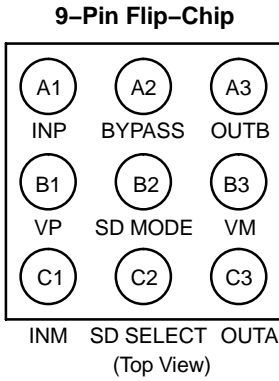


Figure 2. Typical NCP4894 Application Circuit for Driving Earpiece

# NCP4894

## PIN CONNECTIONS



## PIN DESCRIPTION

9-Pin Flip-Chip	Micro-10/DFN10	Type	Symbol	Description
A1	4	I	INP	Positive Differential Input
A2	5	O	BYPASS	Bypass Capacitor Pin which Provides the Common Mode Voltage
A3	6	I	OUTB	Negative BTL Output
B1	9	I	VP	Positive Analog Supply of the Cell
B2	3	I	SD MODE	Shutdown High or Low Selectivity (Note 1)
B3	7	I	VM	Ground
C1	2	I	INM	Negative Differential Input
C2	1	O	SD SELECT	(Note 1)
C3	10	I	OUTA	Positive BTL Output

1. The SD SELECT pin must be toggled to the same state as the SD MODE pin to force the device in shutdown mode.

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## MAXIMUM RATINGS (Note 2)

Rating	Symbol	Value	Unit
Supply Voltage	VP	6.0	V
Operating Supply Voltage	Op VP	2.2 to 5.5 V	–
Input Voltage	V <sub>in</sub>	–0.3 to V <sub>cc</sub> +0.3	V
Max Output Current	I <sub>out</sub>	500	mA
Power Dissipation (Note 3)	P <sub>d</sub>	Internally Limited	–
Operating Ambient Temperature	T <sub>A</sub>	–40 to +85	°C
Max Junction Temperature	T <sub>J</sub>	150	°C
Storage Temperature Range	T <sub>stg</sub>	–65 to +150	°C
Thermal Resistance Junction-to-Air	R <sub>θJA</sub>	200 70 (Note 4)	°C/W
ESD Protection	Human Body Model (HBM) (Note 5) Machine Model (MM) (Note 6)	– > 2000 > 200	V
Latchup Current at T <sub>A</sub> = 85°C (Note 7)	–	±100 mA	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- Maximum electrical ratings are defined as those values beyond which damage to the device may occur at T<sub>A</sub> = +25°C.
- The thermal shutdown set to 160°C (typical) avoids irreversible damage on the device due to power dissipation. For further information see page 7.
- For the 9-Pin Flip-Chip CSP package, the R<sub>θJA</sub> is highly dependent of the PCB Heatsink area. For example, R<sub>θJA</sub> can equal 195°C/W with 50 mm<sup>2</sup> total area and also 135°C/W with 500 mm<sup>2</sup>. For further information see page 10. The bumps have the same thermal resistance and all need to be connected to optimize the power dissipation.
- Human Body Model, 100 pF discharge through a 1.5 kΩ resistor following specification JESD22/A114.
- Machine Model, 200 pF discharged through all pins following specification JESD22/A115.
- Maximum ratings per JEDEC standard JESD78.

# NCP4894

**ELECTRICAL CHARACTERISTICS** Limits apply for  $T_A$  between  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  (Unless otherwise noted).

Characteristic	Symbol	Conditions	Min (Note 8)	Typ	Max (Note 8)	Unit
Supply Quiescent Current	$I_{dd}$	VP = 3.0 V, No Load	–	1.9	–	mA
		VP = 5.0 V, No Load	–	2.1	–	
		VP = 3.0 V, 8.0 $\Omega$	–	2.0	–	
		VP = 5.0 V, 8.0 $\Omega$	–	2.2	4.0	
Common Mode Voltage	$V_{cm}$	–	–	VP/2	–	V
Shutdown Current	$I_{SD}$	For VP between 2.2 V to 5.5 V SDM = SDS = GND $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$	– –	20 –	600 2.0	nA $\mu\text{A}$
SD SELECT Threshold High	$V_{SDIH}$	–	1.4	–	–	V
SD SELECT Threshold Low	$V_{SDIL}$	–	–	–	0.4	V
Turning On Time (Note 10)	$T_{WU}$	$C_{by} = 1.0 \mu\text{F}$	–	140	–	ms
Turning Off Time (Note 10)	$T_{SD}$	–	–	20	–	ms
Output Swing	$V_{loadpeak}$	VP = 3.0 V, $R_L = 8.0 \Omega$	–	2.5	–	V
		VP = 5.0 V, $R_L = 8.0 \Omega$ (Note 9) $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$	4.0 3.85	4.3 –	– –	V
Rms Output Power	$P_O$	VP = 3.0 V, $R_L = 8.0 \Omega$ THD + N < 0.1%	–	0.39	–	W
		VP = 3.3 V, $R_L = 8.0 \Omega$ THD + N < 0.1%	–	0.48	–	
		VP = 5.0 V, $R_L = 8.0 \Omega$ THD + N < 0.1%	–	1.08	–	
Output Offset Voltage	$V_{OS}$	For VP between 2.2 V to 5.5 V	–30	1.0	30	mV
Power Supply Rejection Ratio	PSRR V+	G = 2.0, $R_L = 8.0 \Omega$ VP <sub>ripple_pp</sub> = 200 mV $C_{by} = 1.0 \mu\text{F}$ Input Terminated with 10 $\Omega$				dB
		F = 217 Hz VP = 5.0 V	–	–80	–	
		VP = 3.0 V	–	–80	–	
		F = 1.0 kHz VP = 5.0 V	–	–85	–	
		VP = 3.0 V	–	–85	–	
Efficiency	$\eta$	VP = 3.0 V, $P_{orms} = 380 \text{ mW}$ VP = 5.0 V, $P_{orms} = 1.0 \text{ W}$	– –	64 63	– –	%
Thermal Shutdown Temperature	$T_{sd}$		–	160	–	$^{\circ}\text{C}$
Total Harmonic Distortion	THD	VP = 3.0 V, F = 1.0 kHz $R_L = 8.0 \Omega$ , $A_V = 2.0$ $P_O = 0.32 \text{ W}$	– – –	– 0.007 –	– – –	%
		VP = 5.0 V, F = 1.0 kHz	–	–	–	
		$R_L = 8.0 \Omega$ , $A_V = 2.0$	–	0.006	–	
		$P_O = 1.0 \text{ W}$	–	–	–	

8. Min/Max limits are guaranteed by design, test or statistical analysis.

9. This parameter is not tested in production for 9–Pin Flip–Chip CSP package in case of a 5.0 V power supply, however it is correlated based on a 3.0 V power supply testing.

10. See page 12 for a theoretical approach of these parameters.

TYPICAL PERFORMANCE CHARACTERISTICS

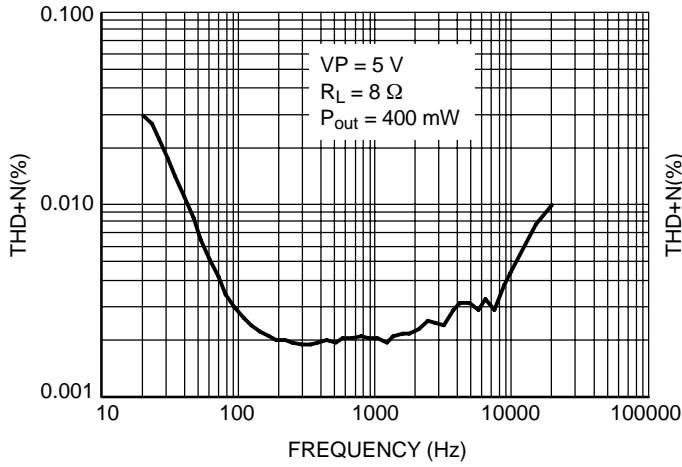


Figure 3. THDN versus Frequency

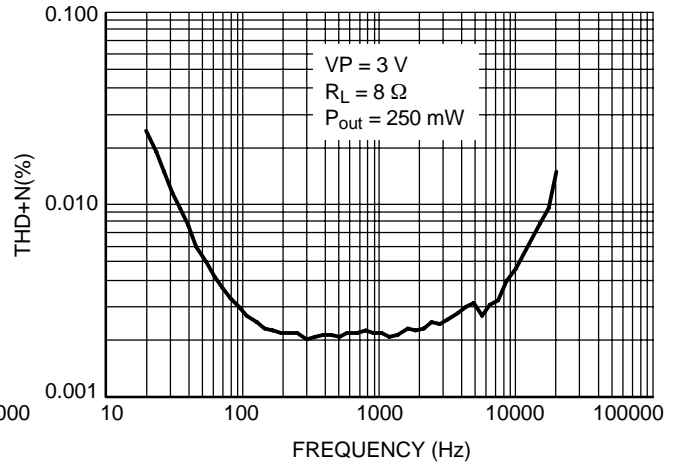


Figure 4. THDN versus Frequency

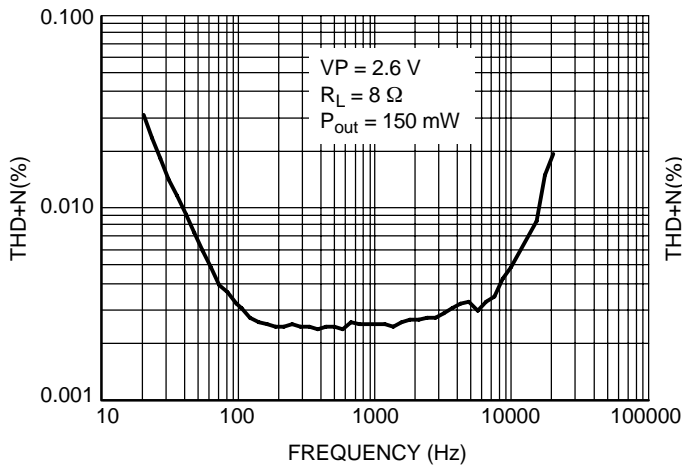


Figure 5. THDN versus Frequency

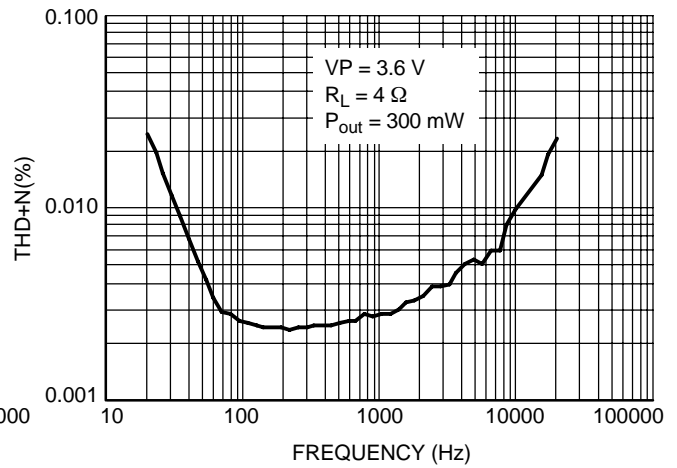


Figure 6. THDN versus Frequency

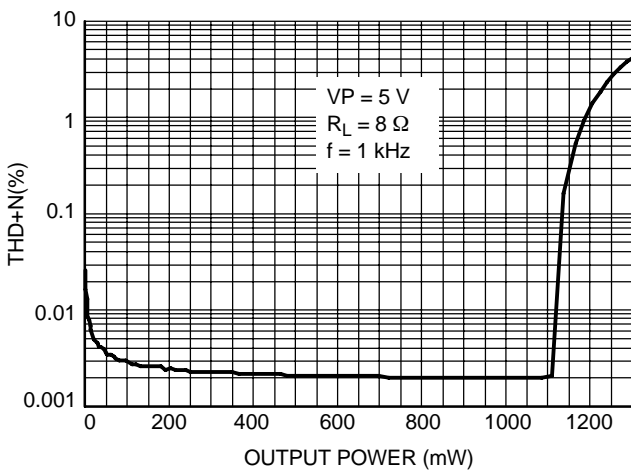


Figure 7. THDN versus Output Power

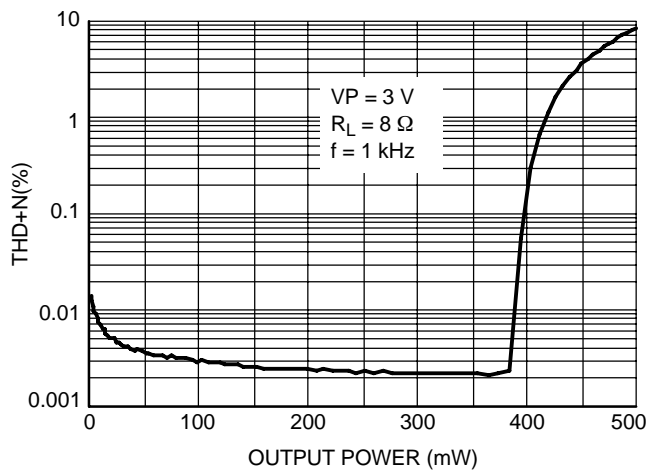


Figure 8. THDN versus Output Power

TYPICAL PERFORMANCE CHARACTERISTICS

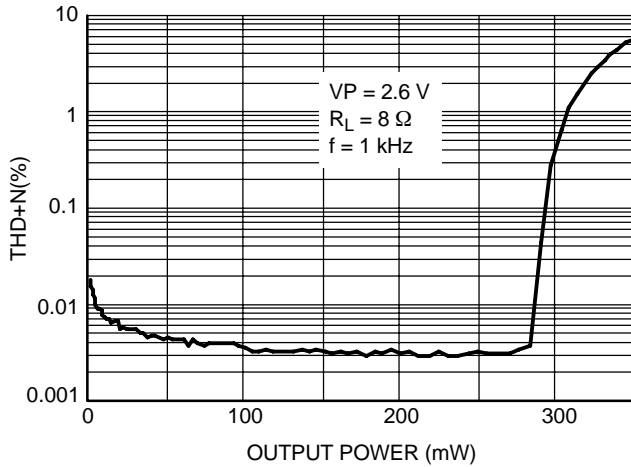


Figure 9. THD+N versus Output Power

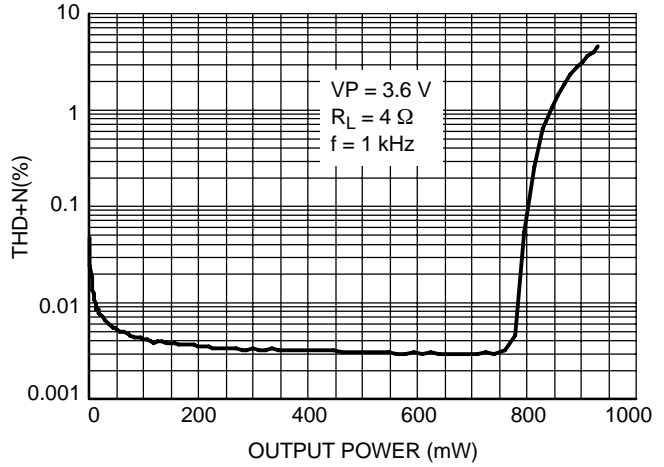


Figure 10. THD+N versus Output Power

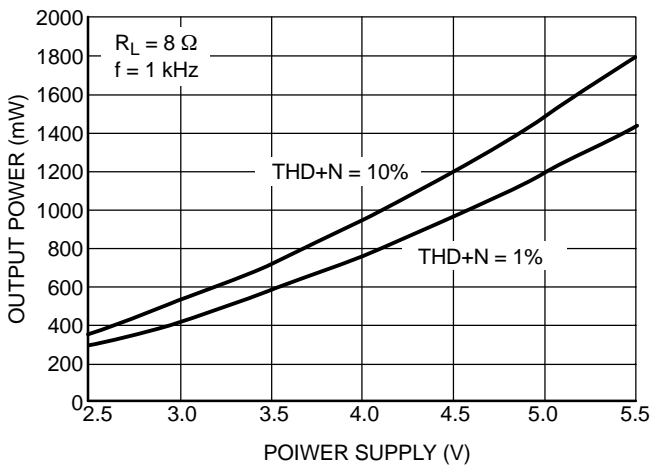


Figure 11. THD+N versus Output Power

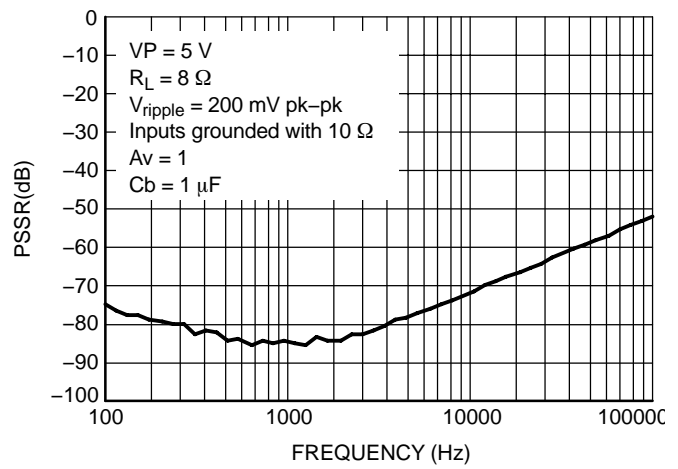


Figure 12. PSRR @ VP = 5 V

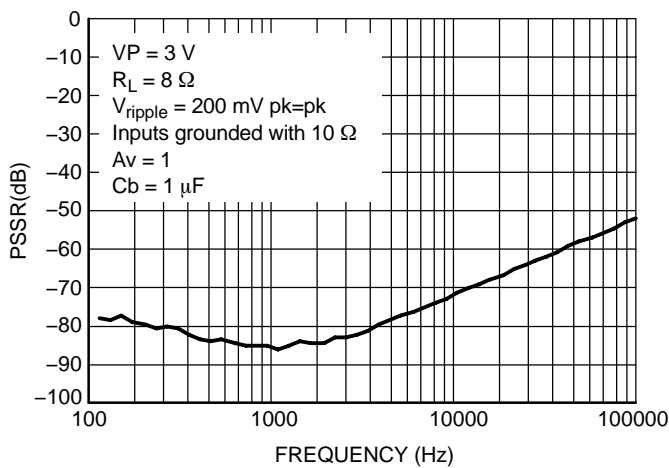


Figure 13. PSRR @ VP = 3 V

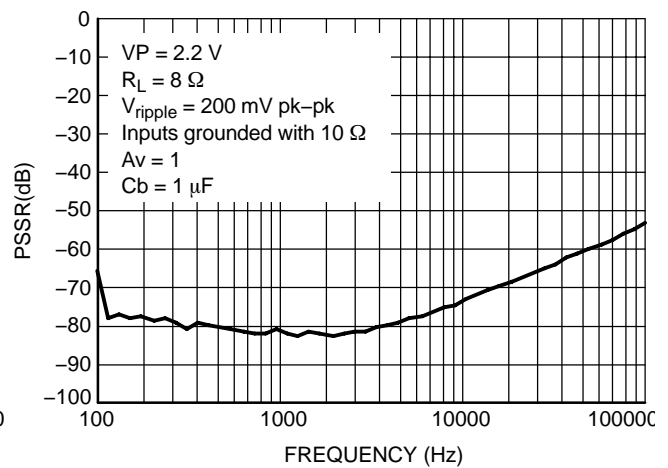


Figure 14. PSRR @ VP = 2.2 V



TYPICAL PERFORMANCE CHARACTERISTICS

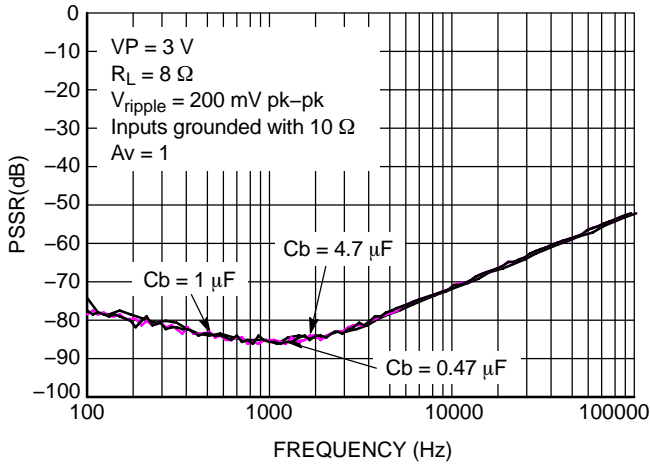


Figure 20. PSRR versus Cb @ VP = 3 V

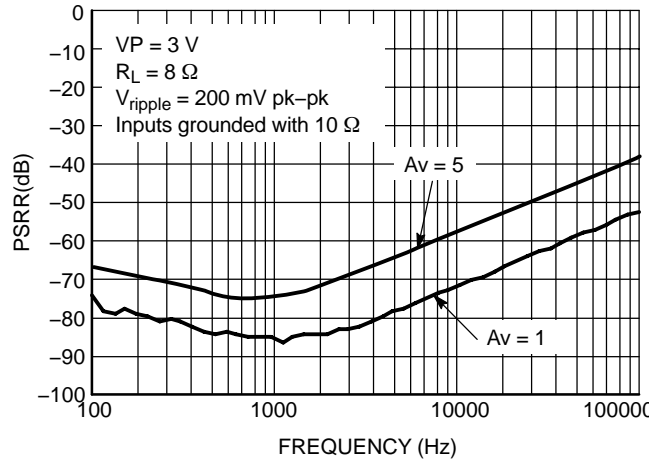


Figure 15. PSRR versus Av @ VP = 3 V

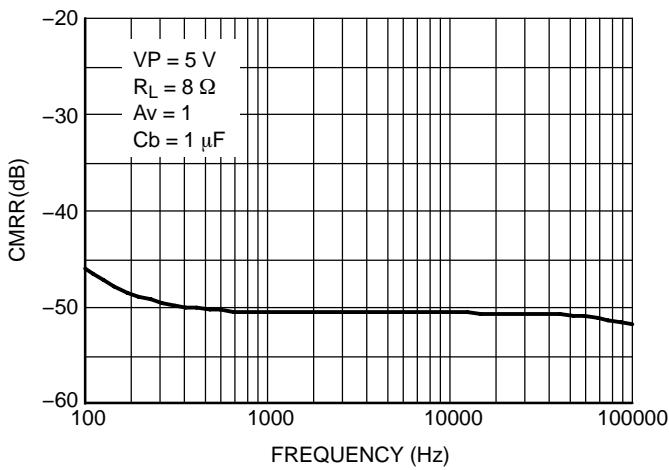


Figure 16. CMRR @ VP = 5 V

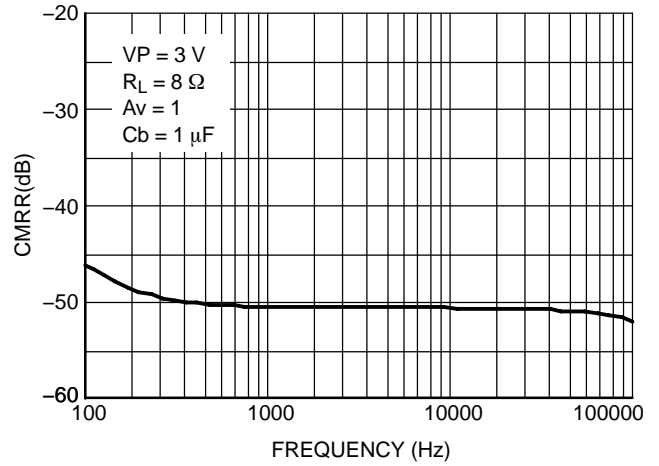


Figure 17. CMRR @ VP = 3 V

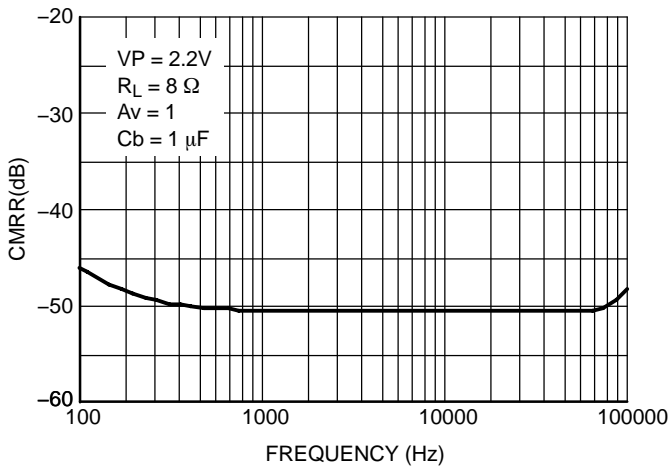


Figure 18. CMRR @ VP = 2.2 V

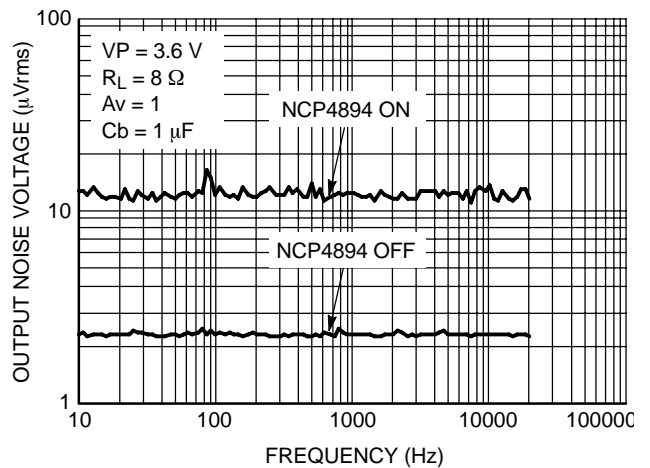
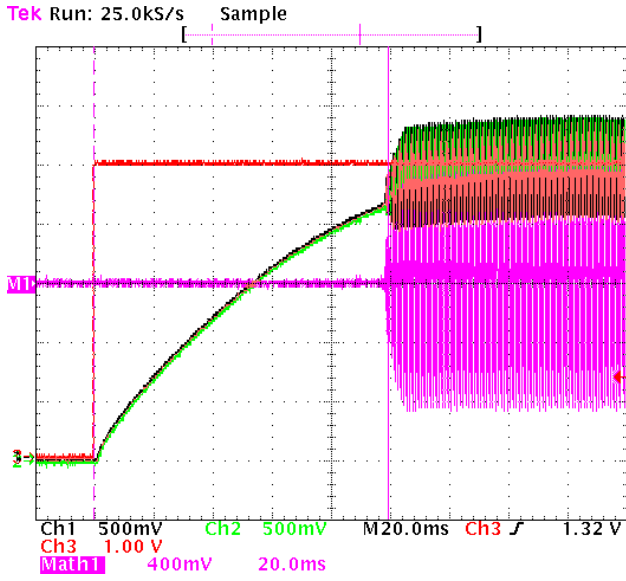


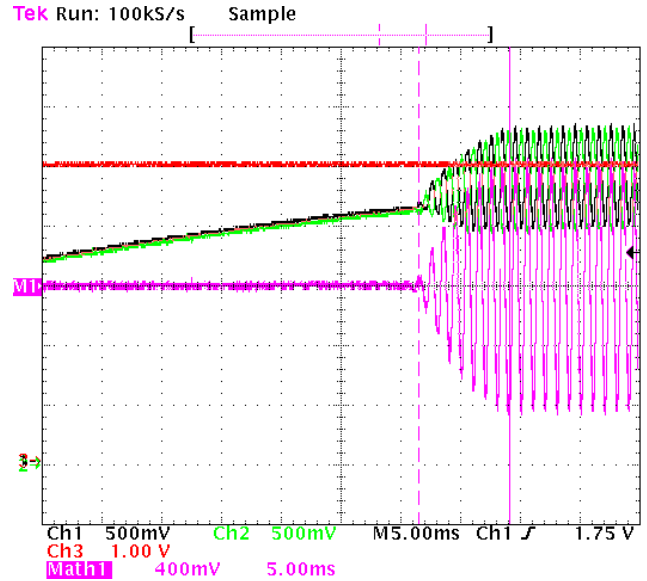
Figure 19. Noise Floor @ VP = 3.6 V

TYPICAL PERFORMANCE CHARACTERISTICS



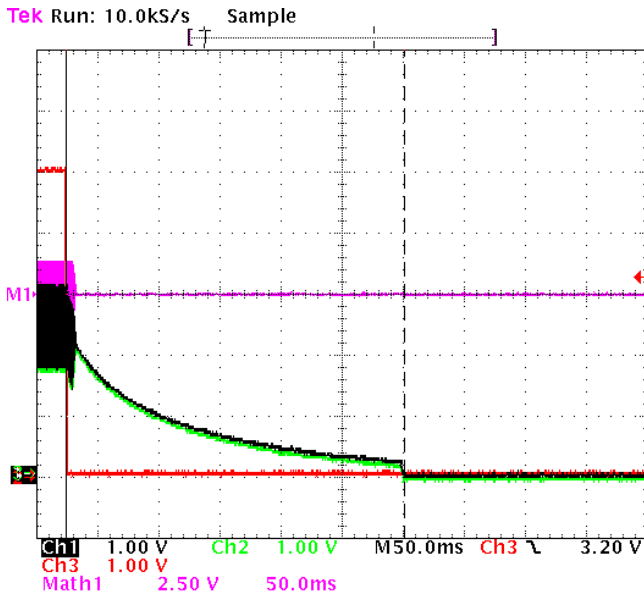
Ch1 = OUTA  
 Ch2 = OUTB  
 Ch3 = Shutdown &  
 Math1 = OUTA-OUTB

Figure 21. Turning-on Sequence  
 @ VP = 5 V and f = 1 kHz



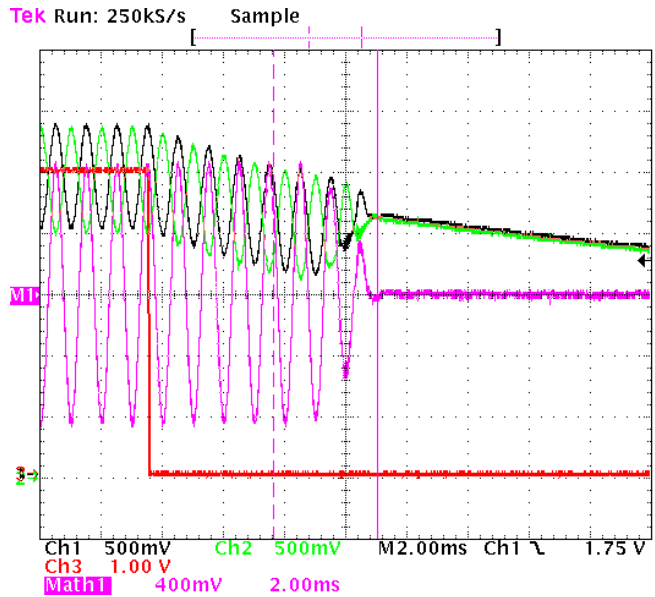
Ch1 = OUTA  
 Ch2 = OUTB  
 Ch3 = Shutdown &  
 Math1 = OUTA-OUTB

Figure 22. Turning-on Sequence Zoom  
 @ VP = 5 V and f = 1 kHz



Ch1 = OUTA  
 Ch2 = OUTB  
 Ch3 = Shutdown &  
 Math1 = OUTA-OUTB

Figure 23. Turning-off Sequence  
 @ VP = 5 V and f = 1 kHz



Ch1 = OUTA  
 Ch2 = OUTB  
 Ch3 = Shutdown &  
 Math1 = OUTA-OUTB

Figure 24. Turning-off Sequence Zoom  
 @ VP = 5 V and f = 1 kHz

TYPICAL PERFORMANCE CHARACTERISTICS

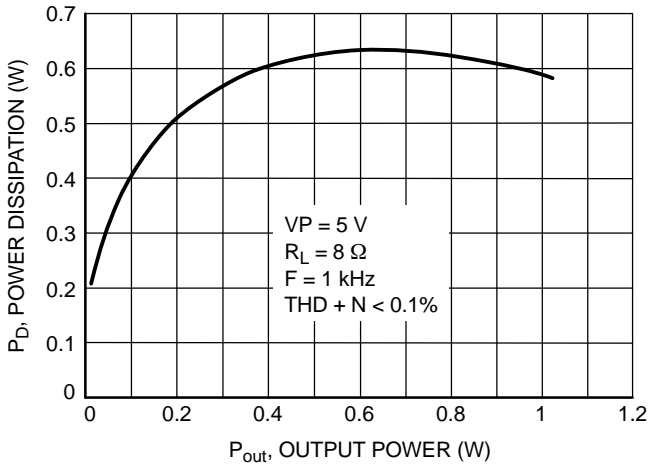


Figure 25. Power Dissipation versus Output Power

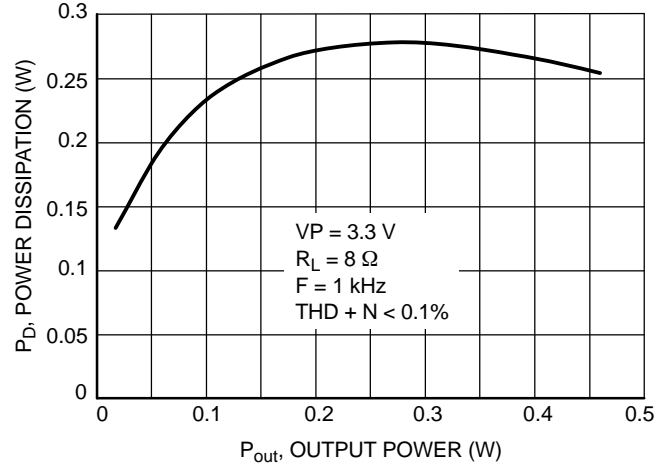


Figure 26. Power Dissipation versus Output Power

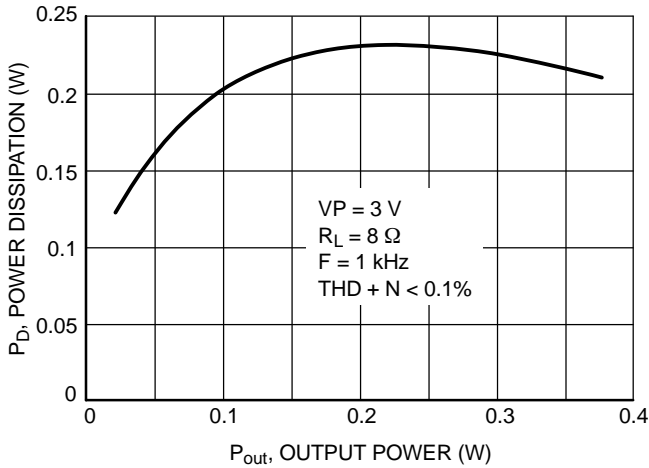


Figure 27. Power Dissipation versus Output Power

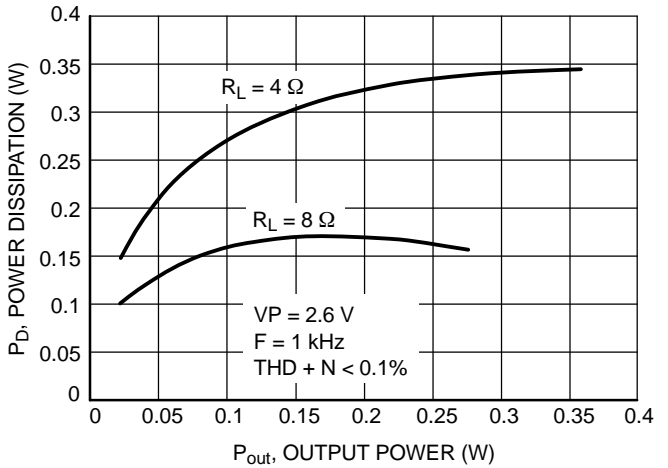


Figure 28. Power Dissipation versus Output Power

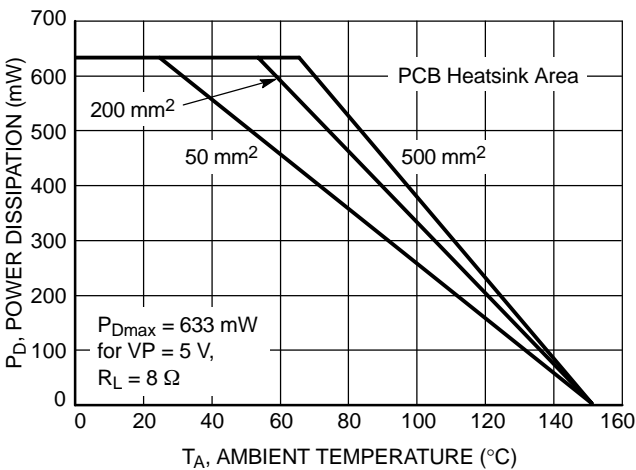


Figure 29. Power Derating – 9-Pin Flip-Chip CSP

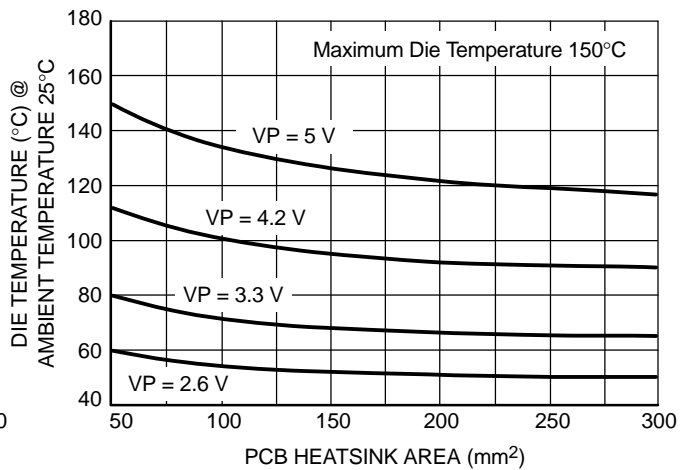


Figure 30. Maximum Die Temperature versus PCB Heatsink Area

## APPLICATION INFORMATION

**Detailed Description**

The NCP4894 audio amplifier can operate under 2.6 V until 5.5 V power supply. It delivers 320 mW rms output power to 4.0  $\Omega$  load ( $V_P = 2.6$  V) and 1.0 W rms output power to 8.0  $\Omega$  load ( $V_P = 5.0$  V).

The structure of the NCP4894 is basically composed of two identical internal power amplifiers. Both are externally configurable with gain-setting resistors  $R_{in}$  and  $R_f$  (the closed-loop gain is fixed by the ratios of these resistors). The load is driven differentially through OUTA and OUTB outputs. This configuration eliminates the need for an output coupling capacitor.

**Internal Power Amplifier**

The output PMOS and NMOS transistors of the amplifier were designed to deliver the output power of the specifications without clipping. The channel resistance ( $R_{on}$ ) of the NMOS and PMOS transistors does not exceed 0.6  $\Omega$  when they drive current.

The structure of the internal power amplifier is composed of three symmetrical gain stages, first and medium gain stages are transconductance gain stages to obtain maximum bandwidth and DC gain.

**Turn-On and Turn-Off Transitions**

A cycle with a turn-on and turn-off transition is illustrated with plots that show both single ended signals on the previous page.

In order to eliminate “pop and click” noises during transitions, output power in the load must be slowly established or cut. When logic high is applied to the shutdown pin, the bypass voltage begins to rise exponentially and once the output DC level is around the common mode voltage, the gain is established slowly (20 ms). Using this turn-on mode, the device is optimized in terms of rejection of “pop and click” noises.

A theoretical value of turn-on time at 25°C is given by the following formula.

$C_{by}$ : bypass capacitor

R: internal 150 k resistor with a 25% accuracy

$$T_{on} = 0.95 * R * C_{by}$$

The device has the same behavior when it is turned-off by a logic low on the shutdown pin. During the shutdown mode, amplifier outputs are connected to the ground. However, to totally cut the output audio signal, you only need to wait for 20 ms.

**Shutdown Function**

The device enters shutdown mode once the SD SELECT and SD MODE pins are in the same logic state. This brings flexibility to the design, as the SD MODE pin must be permanently connected to VP or GND on the PCB. If the SD SELECT pin is not connected to the output of a microcontroller or microprocessor, it's not advisable to let it float. A pulldown or pullup resistor is then suitable.

During the shutdown state, the DC quiescent current has a typical value of 10 nA.

**Current Limit Circuit**

The maximum output power of the circuit ( $P_{orms} = 1.0$  W,  $V_P = 5.0$  V,  $R_L = 8.0$   $\Omega$ ) requires a peak current in the load of 500 mA.

In order to limit the excessive power dissipation in the load when a short-circuit occurs between both outputs, the current limit in the load is fixed to 800 mA.

**Thermal Overload Protection**

Internal amplifiers are switched off when the temperature exceeds 160°C, and will be switched on again only when the temperature decreases below 140°C.

The NCP4894 is unity-gain stable and requires no external components besides gain-setting resistors, an input coupling capacitor and a proper bypassing capacitor in the typical application.

Both internal amplifiers are externally configurable ( $R_f$  and  $R_{in}$ ) with gain configuration.

The differential-ended amplifier presents two major advantages:

- The possible output power is four times larger (the output swing is doubled) as compared to a single-ended amplifier under the same conditions.
- Output pins (OUTA and OUTB) are biased at the same potential  $V_P/2$ , this eliminates the need for an output coupling capacitor required with a single-ended amplifier configuration.

The differential closed loop-gain of the amplifier is given by  $A_{vd} = \frac{R_f}{R_{in}} = \frac{V_{orms}}{V_{inrms}}$ .  $V_{orms}$  is the rms value of the voltage seen by the load and  $V_{inrms}$  is the rms value of the input differential signal.

Output power delivered to the load is given by  $P_{orms} = \frac{(V_{opeak})^2}{2 * R_L}$  ( $V_{opeak}$  is the peak differential output voltage).

When choosing gain configuration to obtain the desired output power, check that the amplifier is not current limited or clipped.

The maximum current which can be delivered to the load is 500 mA  $I_{opeak} = \frac{V_{opeak}}{R_L}$ .

## NCP4894

### Gain-Setting Resistor Selection ( $R_{in}$ and $R_f$ )

$R_{in}$  and  $R_f$  set the closed-loop gain of both amplifiers.

In order to optimize device and system performance, the NCP4894 should be used in low gain configurations.

The low gain configuration minimizes THD + noise values and maximizes the signal to noise ratio, and the amplifier can still be used without running into the bandwidth limitations.

A closed loop gain in the range from 2 to 5 is recommended to optimize overall system performance.

An input resistor ( $R_{in}$ ) value of 22 k $\Omega$  is realistic in most applications, and doesn't require the use of a very large capacitor  $C_{in}$ .

### Input Capacitor Selection ( $C_{in}$ )

The input coupling capacitor blocks the DC voltage at the amplifier input terminal. This capacitor creates a high-pass filter with  $R_{in}$ , the cut-off frequency is given by

$$f_c = \frac{1}{2 * \Pi * R_{in} * C_{in}}$$

The size of the capacitor must be large enough to couple in low frequencies without severe attenuation. However a large input coupling capacitor requires more time to reach its quiescent DC voltage ( $V_P/2$ ) and can increase the turn-on pops.

An input capacitor value between 0.1  $\mu$ F and 0.39  $\mu$ F performs well in many applications (With  $R_{in} = 22$  k $\Omega$ ).

### Bypass Capacitor Selection ( $C_{by}$ )

The bypass capacitor  $C_{by}$  provides half-supply filtering and determines how fast the NCP4894 turns on.

This capacitor is a critical component to minimize the turn-on pop. A 1.0  $\mu$ F bypass capacitor value ( $C_{in} < 0.39$   $\mu$ F) should produce clickless and popless shutdown transitions. The amplifier is still functional with a 0.1  $\mu$ F capacitor value but is more susceptible to "pop and click" noises.

Thus, a 1.0  $\mu$ F bypassing capacitor is recommended.

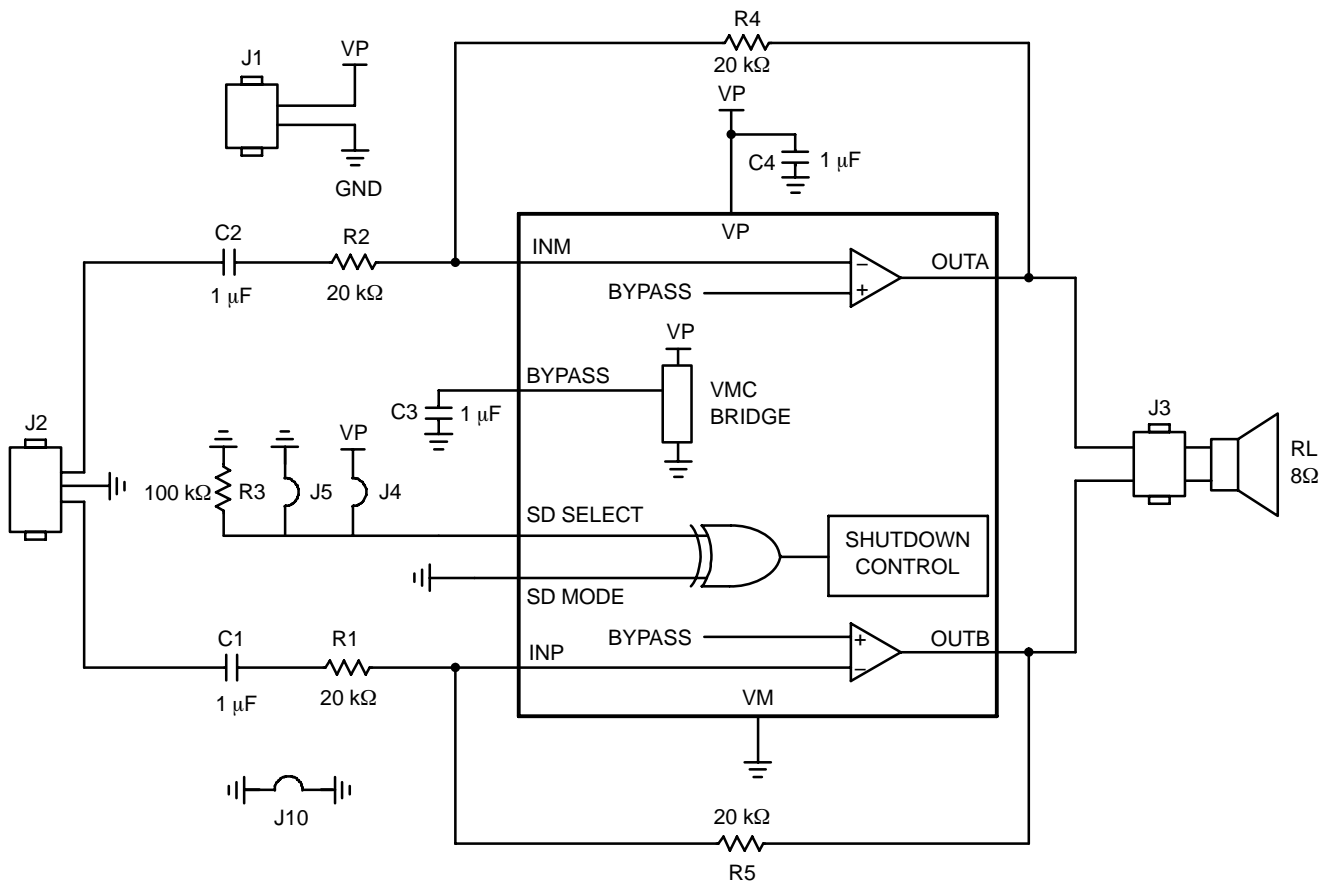
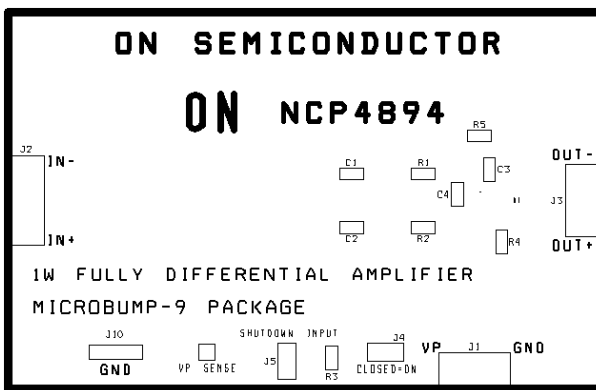
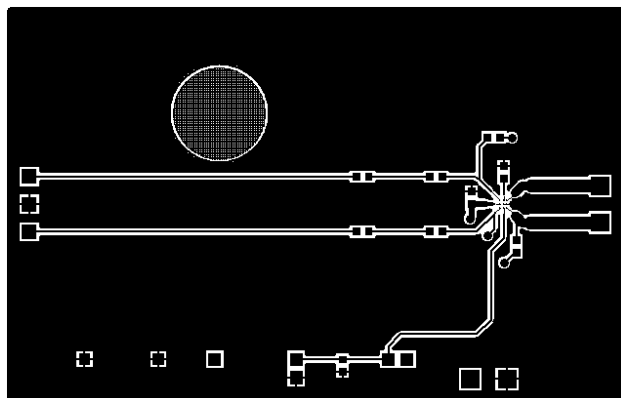


Figure 31. Demonstration Board Schematic

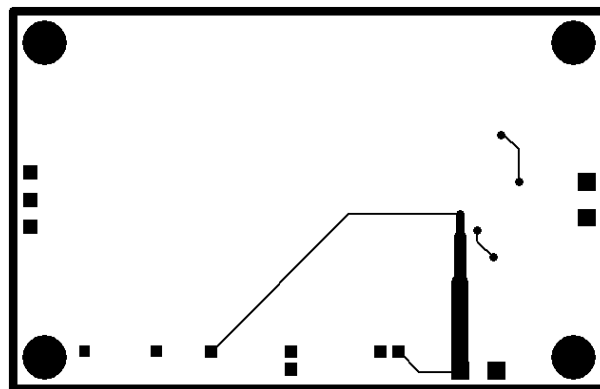
NCP4894



Silkscreen Layer



Top Layer



Bottom Layer

Figure 32. Demonstration Board for 9-Pin Flip-Chip CSP Device – PCB Layers

# NCP4894

## BILL OF MATERIAL

Item	Part Description	Ref	PCB Footprint	Manufacturer	Manufacturer Reference
1	NCP4894 Audio Amplifier	–	–	ON Semiconductor	NCP4894
2	SMD Resistor 100 k $\Omega$	R3	0603	Vishay–Draloric	CRCW0603 Series
3	SMD Resistor 20 k $\Omega$	R1, R2 R4, R5	0603	Vishay–Draloric	CRCW0603 Series
4	Ceramic Capacitor 1.0 $\mu$ F 6.3 V X5R	C1, C2 C3, C4	0603	Murata	GRM188 Series
5	Jumper Header Vertical Mount, 2*1, 100 mils	J4, J5	–	–	–
6	Jumper Connector, 400 mils	J10	–	–	–
7	I/O Connector. It can be plugged by MC–1,5/3–ST–3,81 (Phoenix Contact Reference)	J2	–	Phoenix Contact	MC–1,5/3–G
8	I/O Connector. It can be plugged by BLZ5.08/2 (Weidmüller Reference)	J1, J3	–	Weidmüller	SL5.08/2/90B

## ORDERING INFORMATION

Device	Marking	Package	Shipping†
NCP4894FCT1	MAI	9–Pin Flip–Chip	3000 / Tape & Reel
NCP4894FCT1G	MAI	9–Pin Flip–Chip (Pb–Free)	3000 / Tape & Reel
NCP4894DMR2	MAK	Micro–10	4000 / Tape & Reel
NCP4894DMR2G	MAK	Micro–10 (Pb–Free)	4000 / Tape & Reel
NCP4894MNR2	4894	DFN10	3000 / Tape & Reel
NCP4894MNR2G	4894	DFN10 (Pb–Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NOTE: This product is offered with either eutectic (SnPb–tin/lead) or lead–free solder bumps (G suffix) depending on the PCB assembly process. The NCP4894FCT1G, NCP4894DMR2G, NCP4894MNR2G version requires a lead–free solder paste and should not be used with a SnPb solder paste.

# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

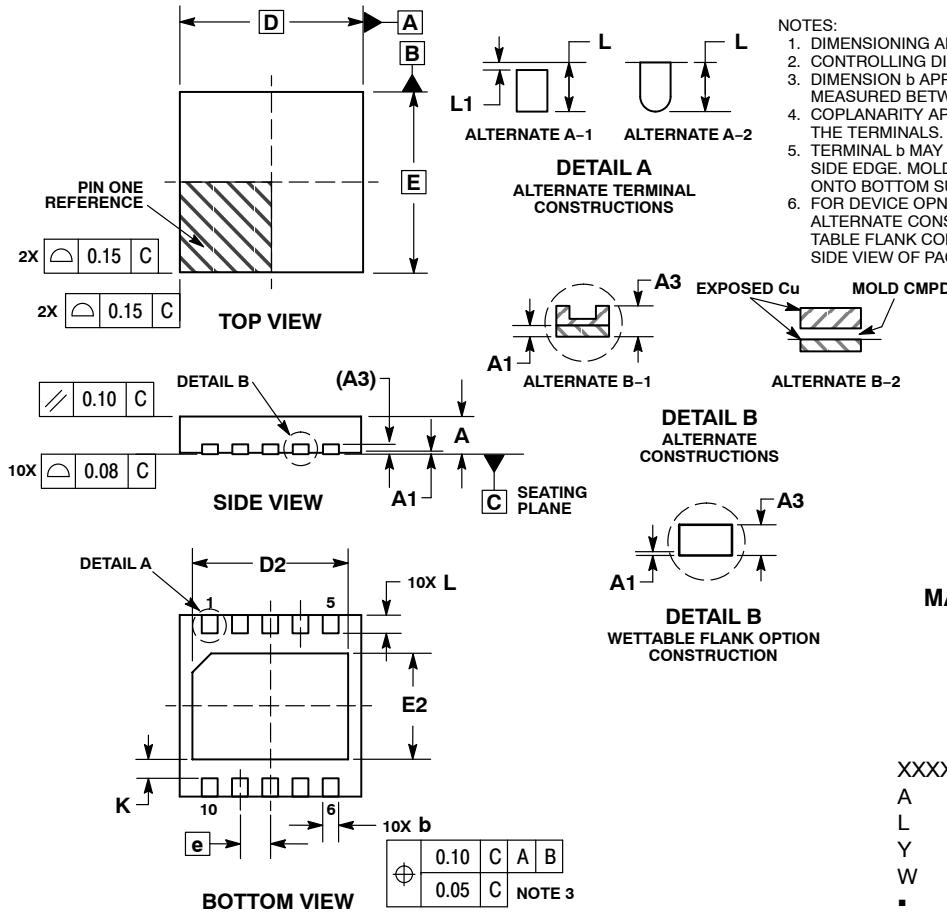
ON Semiconductor®



SCALE 2:1

DFN10, 3x3, 0.5P  
CASE 485C  
ISSUE E

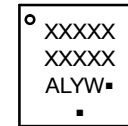
DATE 11 FEB 2016



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL.
  4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
  5. TERMINAL b MAY HAVE MOLD COMPOUND MATERIAL ALONG SIDE EDGE. MOLD FLASHING MAY NOT EXCEED 30 MICRONS ONTO BOTTOM SURFACE OF TERMINAL b.
  6. FOR DEVICE OPN CONTAINING W OPTION, DETAIL A AND B ALTERNATE CONSTRUCTION ARE NOT APPLICABLE. WETTABLE FLANK CONSTRUCTION IS DETAIL B AS SHOWN ON SIDE VIEW OF PACKAGE.

MILLIMETERS		
DIM	MIN	MAX
A	0.80	1.00
A1	0.00	0.05
A3	0.20	REF
b	0.18	0.30
D	3.00	BSC
D2	2.40	2.60
E	3.00	BSC
E2	1.70	1.90
e	0.50	BSC
K	0.19	TYP
L	0.35	0.45
L1	0.00	0.03

### GENERIC MARKING DIAGRAM\*

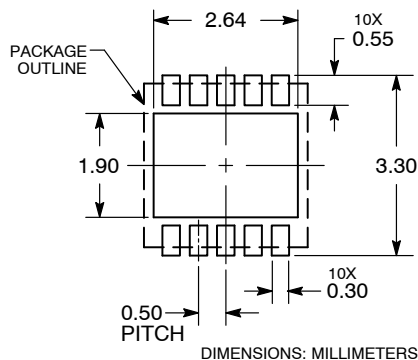


- XXXXXX = Specific Device Code
- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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<b>DESCRIPTION:</b>	<b>DFN10, 3X3 MM, 0.5 MM PITCH</b>	<b>PAGE 1 OF 1</b>

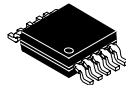
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# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

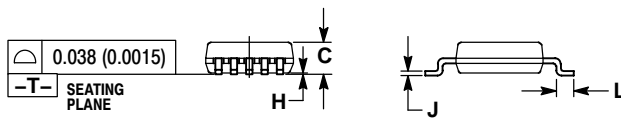
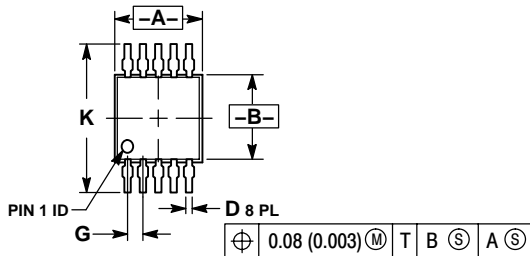
ON Semiconductor®



SCALE 2:1

**Micro10**  
CASE 846B-03  
ISSUE D

DATE 07 DEC 2004



**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION "A" DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION "B" DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. 846B-01 OBSOLETE. NEW STANDARD 846B-02

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	0.95	1.10	0.037	0.043
D	0.20	0.30	0.008	0.012
G	0.50 BSC		0.020 BSC	
H	0.05	0.15	0.002	0.006
J	0.10	0.21	0.004	0.008
K	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

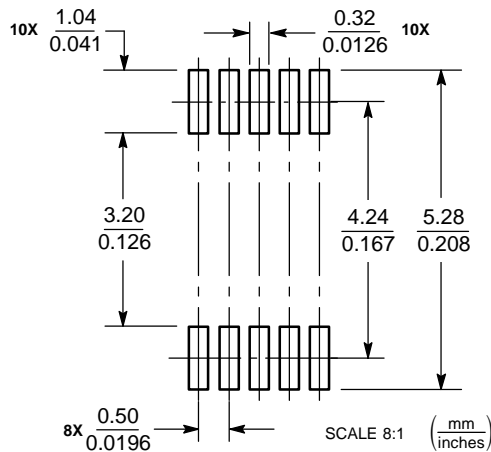
**GENERIC MARKING DIAGRAM\***



- xxxx = Device Code
- A = Assembly Location
- Y = Year
- W = Work Week
- = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present.

**SOLDERING FOOTPRINT**



**Micro10**

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<b>NEW STANDARD:</b>		
<b>DESCRIPTION:</b>	<b>Micro10</b>	<b>PAGE 1 OF 2</b>



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